74HC244; 74HCT244

Octal buffer/line driver; 3-state

Rev. 4 — 24 September 2012

Product data sheet

1. **General description**

The 74HC244; 74HCT244 is an 8-bit buffer/line driver with 3-state outputs. The device can be used as two 4-bit buffers or one 8-bit buffer. The device features two output enables (10E and 20E), each controlling four of the 3-state outputs. A HIGH on nOE causes the outputs to assume a high-impedance OFF-state. Inputs include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

Features and benefits 2.

- Input levels:
 - ◆ For 74HC244: CMOS level
 - ◆ For 74HCT244: TTL level
- Octal bus interface
- Non-inverting 3-state outputs
- Complies with JEDEC standard no. 7 A
- ESD protection:
 - ♦ HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

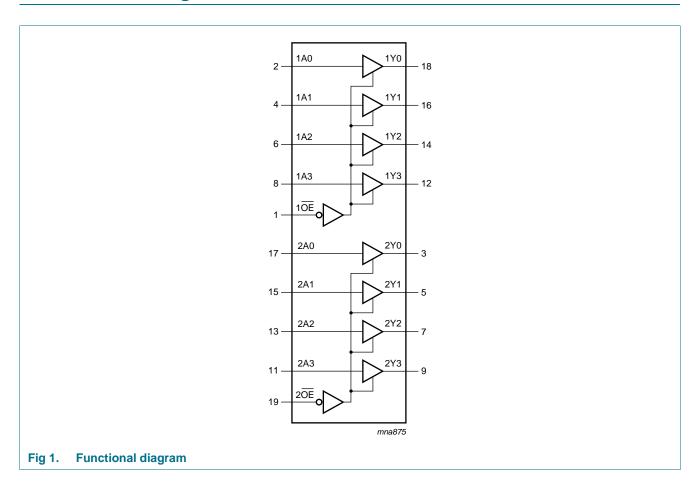
Ordering information 3.

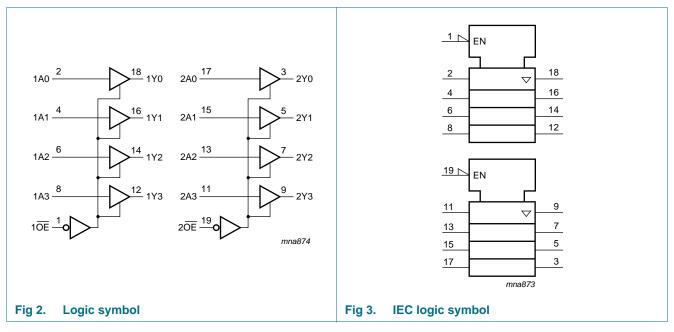
Ordering information Table 1.

Type number	Package			
	Temperature range	Name	Description	Version
74HC244N	–40 °C to +125 °C	DIP20	plastic dual in-line package; 20 leads (300 mil)	SOT146-1
74HCT244N				
74HC244D	–40 °C to +125 °C	SO20	plastic small outline package; 20 leads;	SOT163-1
74HCT244D			body width 7.5 mm	
74HC244DB	−40 °C to +125 °C	SSOP20	plastic shrink small outline package; 20 leads;	SOT339-1
74HCT244DB			body width 5.3 mm	
74HC244PW	−40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20 leads;	SOT360-1
74HCT244PW			body width 4.4 mm	
74HC244BQ	–40 °C to +125 °C	DHVQFN20	plastic dual-in-line compatible thermal enhanced	SOT764-1
74HCT244BQ			very thin quad flat package; no leads; 20 terminals; body $2.5 \times 4.5 \times 0.85$ mm	



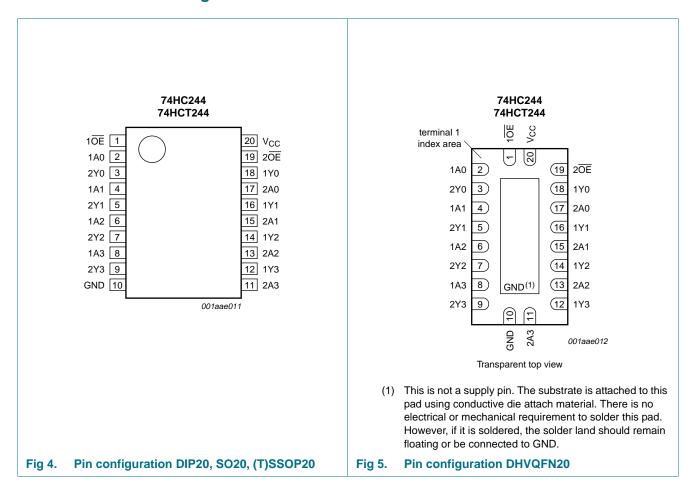
4. Functional diagram





5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1 OE , 2 OE	1, 19	output enable input (active LOW)
1A0, 1A1, 1A2, 1A3	2, 4, 6, 8	data input
2Y0, 2Y1, 2Y2, 2Y3	3, 5, 7, 9	bus output
GND	10	ground (0 V)
2A0, 2A1, 2A2, 2A3	17, 15, 13, 11	data input
1Y0, 1Y1, 1Y2, 1Y3	18, 16, 14, 12	bus output
V _{CC}	20	supply voltage

6. Functional description

Table 3. Function table[1]

Input nOE	Output	
nOE	nAn	nYn
L	L	L
L	Н	Н
Н	X	Z

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I _{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I _O	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	-	±35	mA
I _{CC}	supply current		-	70	mA
I_{GND}	ground current		-70	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	DIP20 package	[1] -	750	mW
		SO20, SSOP20, TSSOP20 and DHVQFN20 packages	[2] _	500	mW

^[1] For DIP20 package: Ptot derates linearly with 12 mW/K above 70 °C.

For SSOP20 and TSSOP20 packages: P_{tot} derates linearly with 5.5 mW/K above 60 $^{\circ}\text{C}.$

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
74HC244						
V_{CC}	supply voltage		2.0	5.0	6.0	V
VI	input voltage		0	-	V_{CC}	V
Vo	output voltage		0	-	V_{CC}	V
$\Delta t/\Delta V$	input transition rise and fall rate	V _{CC} = 2.0 V	-	-	625	ns/V
		V _{CC} = 4.5 V	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	ns/V
T _{amb}	ambient temperature		-40	-	+125	°C

74HC_HCT244

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^[2] For SO20 packages: P_{tot} derates linearly with 8 mW/K above 70 °C.

For DHVQFN20 packages: above 60 °C, Ptot derates linearly with 4.5 mW/K.

 Table 5.
 Recommended operating conditions ...continued

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
74HCT244						
V _{CC}	supply voltage		4.5	5.0	5.5	V
VI	input voltage		0	-	V_{CC}	V
Vo	output voltage		0	-	V_{CC}	V
Δt/ΔV	input transition rise and	fall rate V _{CC} = 4.5 V	-	1.67	139	ns/V
T _{amb}	ambient temperature		-40	-	+125	°C

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C to	+85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC24	4							1		
V_{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V_{IL}	LOW-level	V _{CC} = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V_{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_{O} = -20 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_{O} = -20 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -20 \mu A; V_{CC} = 6.0 V$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	3.84	-	3.7	-	V
		$I_{O} = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	5.34	-	5.2	-	V
V_{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_O = 20 \mu A; V_{CC} = 2.0 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 6.0 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	-	0.33	-	0.4	V
		$I_O = 7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
l _{OZ}	OFF-state output current	per input pin; $V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND; other inputs at V_{CC} or GND; $V_{CC} = 6.0 \text{ V}$; $I_O = 0 \text{ A}$	-	-	±0.5	-	±5.0	-	±10	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	8.0	-	80	-	160	μΑ
C _I	input capacitance		-	3.5	-	-	-	-	-	pF

 Table 6.
 Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C to	+85 °C	–40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HCT2	44				•			'		
V _{IH}	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	1.6	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	1.2	0.8	-	8.0	-	8.0	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -6 \text{ mA}$	3.98	4.32	-	3.84	-	3.7	-	V
V_{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	$I_O = 20 \mu A$	-	0	0.1	-	0.1	-	0.1	V
		$I_{O} = 6.0 \text{ mA}$	-	0.16	0.26	-	0.33	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I _{OZ}	OFF-state output current	per input pin; $V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND; other inputs at V_{CC} or GND; $V_{CC} = 5.5 \text{ V}$; $I_O = 0 \text{ A}$	-	-	±0.5	-	±5.0	-	±10	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5$ V; $I_O = 0$ A	-	-	8.0	-	80	-	160	μΑ
Δl _{CC}	additional supply current	per input pin; $V_{I} = V_{CC} - 2.1 \text{ V};$ other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V};$ $I_{O} = 0 \text{ A}$	-	70	252	-	315	-	343	μΑ
C _I	input capacitance		-	3.5	-	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

GND = 0 V; for load circuit see <u>Figure 8</u>.

Symbol	Parameter	Conditions			25 °C		-40 °C to	-40 °C to +125 °C		
				Min	Тур	Max	Max (85 °C)	Max (125 °C)		
74HC244	1		,							
t _{pd} pro	propagation delay	nAn to nYn;	<u>[1]</u>							
		see Figure 6								
		$V_{CC} = 2.0 \text{ V}$		-	30	110	145	165	ns	
		V _{CC} = 4.5 V		-	11	22	28	33	ns	
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	9	-	-	-	ns	
		$V_{CC} = 6.0 \text{ V}$		-	9	19	24	28	ns	

 Table 7.
 Dynamic characteristics ...continued

GND = 0 V; for load circuit see Figure 8.

Symbol	Parameter	Conditions			25 °C		-40 °C to	+125 °C	Uni
				Min	Тур	Max	Max (85 °C)	Max (125 °C)	
t _{en}	enable time	nOE to nYn; see Figure 7	[2]			1			
		V _{CC} = 2.0 V		-	36	150	190	225	ns
		V _{CC} = 4.5 V		-	13	30	38	45	ns
		$V_{CC} = 6.0 \text{ V}$		-	10	26	33	38	ns
t _{dis}	disable time	nOE to nYn or see Figure 7	[3]						
		V _{CC} = 2.0 V		-	39	150	190	225	ns
		V _{CC} = 4.5 V		-	14	30	38	45	ns
		V _{CC} = 6.0 V		-	11	26	33	38	ns
t _t	transition time	see Figure 6							
		V _{CC} = 2.0 V		-	14	60	75	90	ns
		V _{CC} = 4.5 V		-	5	12	15	18	ns
		V _{CC} = 6.0 V		-	4	10	13	15	ns
C _{PD}	power dissipation capacitance	per buffer; $V_I = GND$ to V_{CC}	<u>[5]</u>	-	35	-	-	-	pF
74HCT24	14								
t _{pd}	propagation delay	nAn to nYn;	<u>[1]</u>						
		see Figure 6							
		V _{CC} = 4.5 V		-	13	22	28	33	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	11	-	-	-	ns
t _{en}	enable time	$\overline{\text{OE}}$ to nYn; $V_{\text{CC}} = 4.5 \text{ V}$; see Figure 7	[2]	-	15	30	38	45	ns
t _{dis}	disable time	\overline{OE} to nYn; $V_{CC} = 4.5 \text{ V}$; see Figure 7	[3]	-	15	25	31	38	ns
t	transition time	V _{CC} = 4.5 V; see <u>Figure 6</u>	[4]	-	5	12	15	18	ns
C _{PD}	power dissipation capacitance	per buffer; V _I = GND to V _{CC} – 1.5 V	<u>[5]</u>	-	35	-	-	-	pF

^[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

[5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

 $P_D = C_{PD} \times V_{CC}{}^2 \times f_i \times N + \sum \left(C_L \times V_{CC}{}^2 \times f_o \right)$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 \sum (C_L \times V_{CC}² \times f_o) = sum of outputs.

^[2] t_{en} is the same as t_{PZH} and t_{PZL} .

^[3] t_{dis} is the same as t_{PHZ} and t_{PLZ} .

^[4] t_t is the same as t_{THL} and t_{TLH} .

11. Waveforms

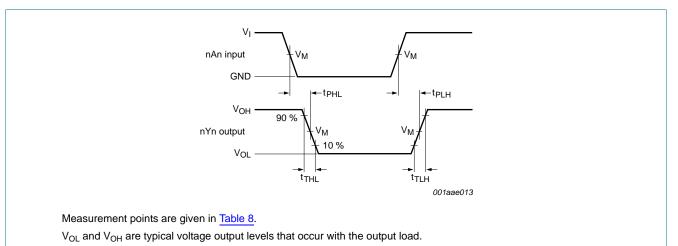


Fig 6. Input (nAn) to output (nYn) propagation delays and output transition times

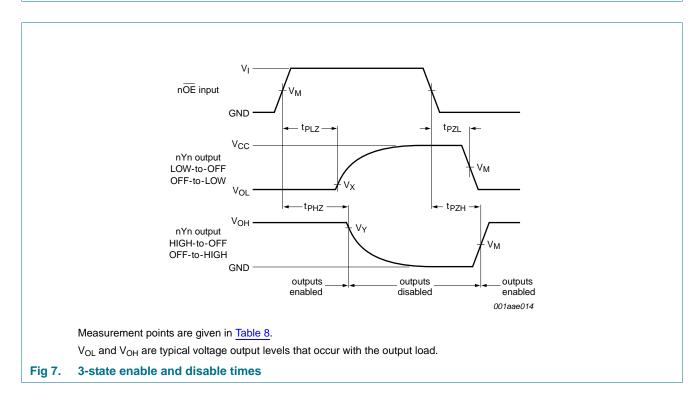
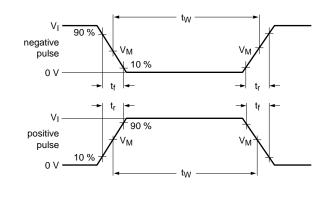
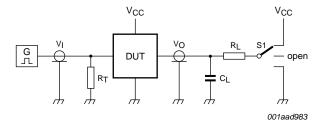


Table 8. Measurement points

Туре	Input	Output		
	V _M	V _M	V _X	V _Y
74HC244	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	$0.1 \times V_{CC}$	$0.9 \times V_{CC}$
74HCT244	1.3 V	1.3 V	$0.1 \times V_{CC}$	$0.9 \times V_{CC}$





Test data is given in Table 9.

Definitions test circuit:

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance.

R_L = Load resistance.

S1 = Test selection switch.

Fig 8. Test circuit for measuring switching times

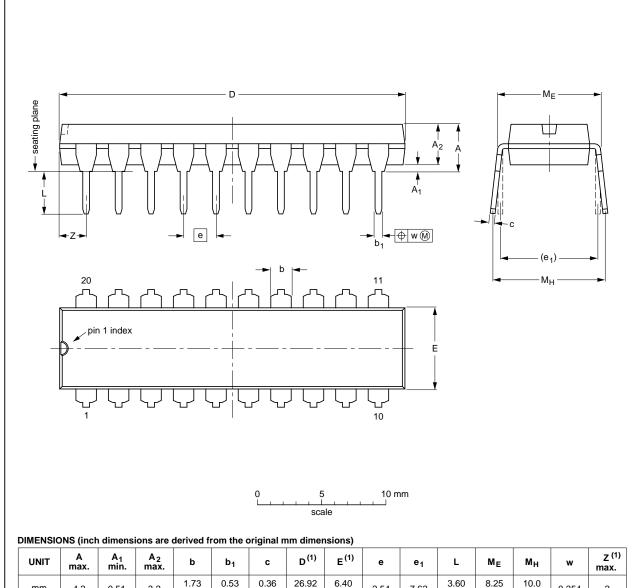
Table 9. Test data

Туре	Input		Load		S1 position			
	VI	t _r , t _f	CL	R_L	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}	
74HC244	V_{CC}	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}	
74HCT244	3 V	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}	

12. Package outline

DIP20: plastic dual in-line package; 20 leads (300 mil)

SOT146-1



	•					•									
UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	С	D ⁽¹⁾	E ⁽¹⁾	e	e ₁	L	ME	Мн	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	0.36 0.23	26.92 26.54	6.40 6.22	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2
inches	0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.014 0.009	1.060 1.045	0.25 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.078

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	
SOT146-1		MS-001	SC-603		99-12-27 03-02-13

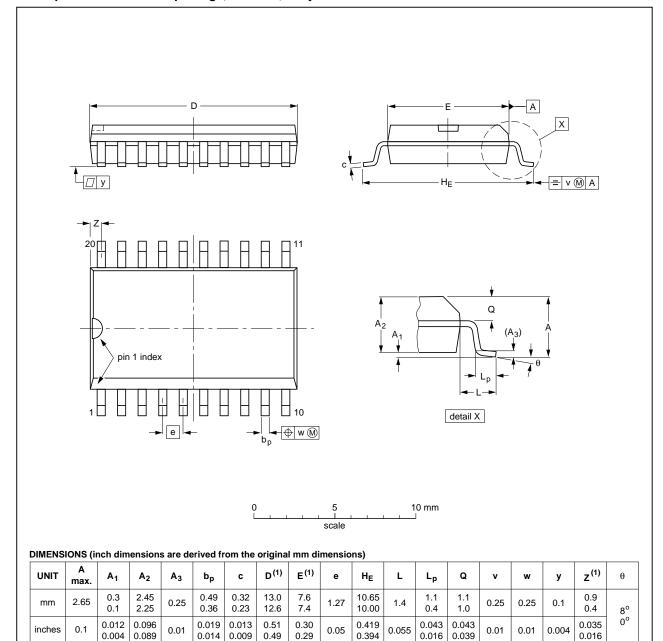
Fig 9. Package outline SOT146-1 (DIP20)

74HC_HCT244

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SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT163-1	075E04	MS-013			99-12-27 03-02-19	

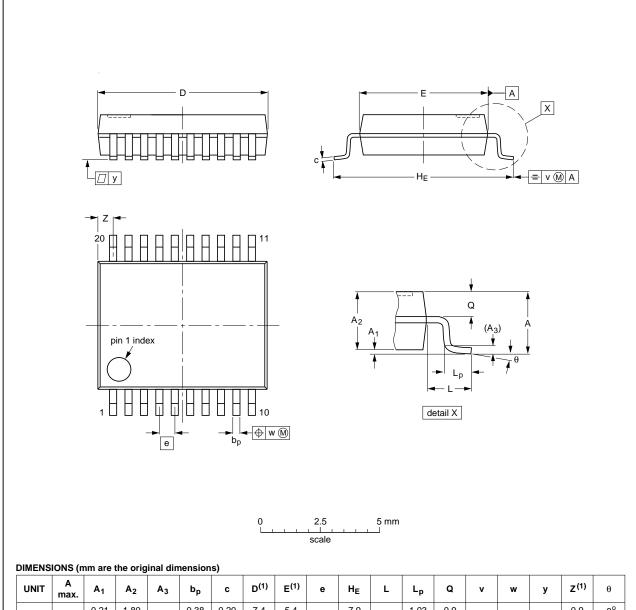
Fig 10. Package outline SOT163-1 (SO20)

74HC_HCT244

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SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	7.4 7.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	0.9 0.5	8° 0°

Note

1. Plastic or metal protrusions of 0.2 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT339-1		MO-150				99-12-27 03-02-19

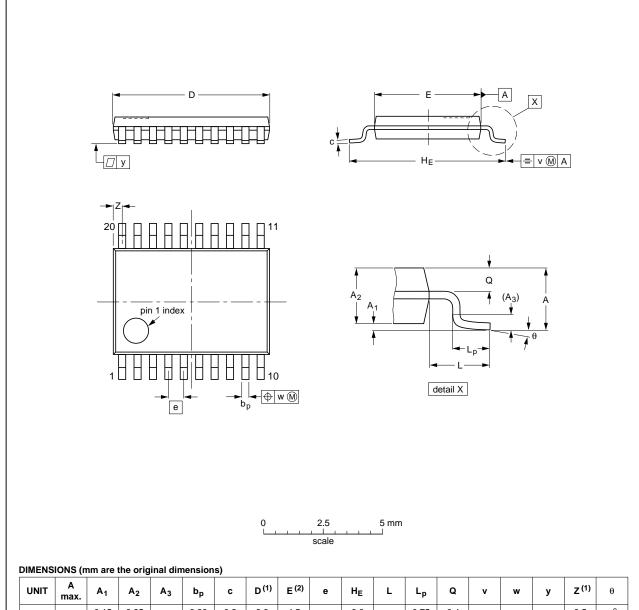
Fig 11. Package outline SOT339-1 (SSOP20)

74HC_HCT244

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TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1



				,		-,												
UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E (2)	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	6.6 6.4	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT360-1		MO-153				99-12-27 03-02-19	
					1	03-02-19	,

Fig 12. Package outline SOT360-1 (TSSOP20)

74HC_HCT244

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DHVQFN20: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 x 4.5 x 0.85 mm SOT764-1

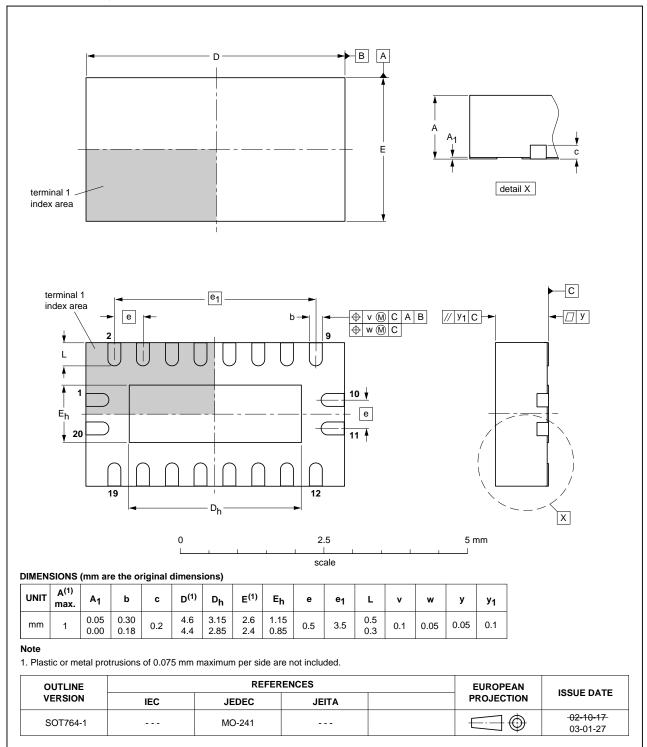


Fig 13. Package outline SOT764-1 (DHVQFN20)

74HC_HCT244

13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74HC_HCT244 v.4	20120924	Product data sheet	-	74HC_HCT244 v.3		
Modifications:	 The format of this data sheet has been redesigned to comply with the new i guidelines of NXP Semiconductors. Legal texts have been adapted to the new company name where appropria 					
74HC_HCT244 v.3	20051222	Product data sheet	-	74HC_HCT244_CNV v.2		
74HC_HCT244_CNV v.2	19901201	Product specification	-	-		

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

15.2 Definitions

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For sales office addresses, please send an email to: salesaddresses@nxp.com

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